



# Space Charge Limited Current Scaling for Short-Pulse Beam in a Vacuum Diode with Different Pulse Shapes

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## Summary

- We study how **space charge** influences short pulse **beam dynamics**, examining different **profiles**, charge densities, and widths. We analyze electron sheet trajectories and pulse profile changes during gap transit.

## Multiple-Sheet Model

A one-dimensional (1D) planar diode with gap distance  $d$  and gap voltage  $V_g$  with  $M$  sheets inside.

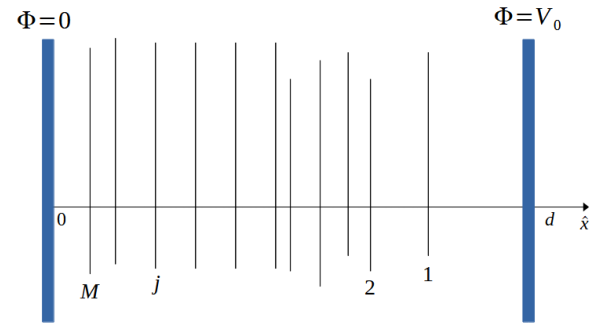


Figure 1: Sheet numbering inside the diode gap [1]

- Sheet  $j$  at position  $\bar{x}_j = x_j/d$  has a normalized charge density  $\bar{\rho}_j = \rho/\sigma_1$ .
- The Electric field on sheet  $j$  is

$$E_j = E_0 + \frac{1}{\epsilon_0} \left( \sum_{i=1}^M \rho_i \frac{x_i}{d} - \sum_{i=1}^{j-1} \rho_i + \frac{1}{2} \rho_j \right)$$

- The Electric field at the cathode ( $x = 0$ )

$$E_c = E_0 - \frac{1}{\epsilon_0} \sum_{i=1}^M \rho_i \left( 1 - \frac{x_i}{d} \right)$$

- The Space Charge Limited (SCL) charge density  $\rho_{i,SCL}$  is found  $E$

$$\sum_{i=1}^M \rho_{i,SCL} \left( 1 - \frac{x_i}{d} \right) = \rho_{SCL}$$

## Model Parameters

Symbol	Meaning	Value
$d$	Gap distance	1.5 mm
$V_0$	Applied voltage	30 kV
$M$	Number of sheets	40
$\eta$	Electron q/m ratio	$1.7588 \times 10^{11} \text{C/kg}$

## Square-top Profile

- Sheets have **equal charge density**  $\bar{\rho}$
- The charge density  $\bar{\rho}^*$  is found from (3)

$$\bar{\rho}^* = \frac{1}{M} \left[ \frac{1}{1 - \delta\bar{x} \left( \frac{M-1}{2} \right)} \right] \quad (4)$$

- We simulate 40 preloaded sheets inside the gap. The initial pulse intervals  $\delta\bar{x} = \bar{x}_n - \bar{x}_{n+1}$  are assumed to be uniform

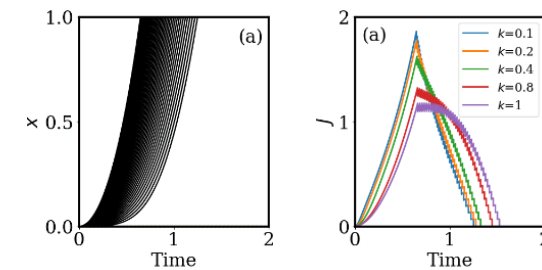


Figure 2: Trajectories & current density for  $T_0$  and  $\bar{\rho}^*$

## Trapezoidal Profile

- A **more general square-top model** that include a time of rise and a time of fall

$$\rho_j = \begin{cases} \rho_0 + (j-1) \frac{\rho_1 - \rho_0}{n_r}, & 1 \leq j < n_r \\ \rho_1, & n_r \leq j < (M - n_f) \\ \rho_0 + (M-j) \frac{\rho_1 - \rho_0}{n_f}, & (M - n_f) \leq j \leq M \end{cases}$$

- $\rho_0$  and  $\rho_1$  are respectively the lowest and highest charge density.

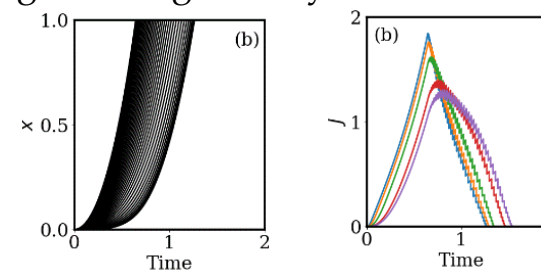


Figure 3: Trajectories & current density for  $T_0$  and  $\bar{\rho}^*$

## Gaussian Profile

- Sheet  $j$  has a **charge density**

$$\bar{\rho}_j = a \exp \left[ -\frac{(j-\mu)^2}{b} \right] \quad (5)$$

where  $\mu = (M+1)/2$ ,  $a$  and  $b$  are found by solving (3) with  $\sum_{i=1}^M \bar{\rho}_i^* = 1$ . (as the bulk of sheets tends to combine, looking like a single sheet).

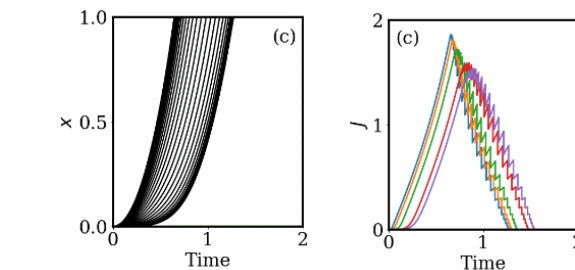


Figure 4: Trajectories & current density for  $T_0$  and  $\bar{\rho}^*$

## Pulse profiles distortion

Distortion  $\propto f/k$

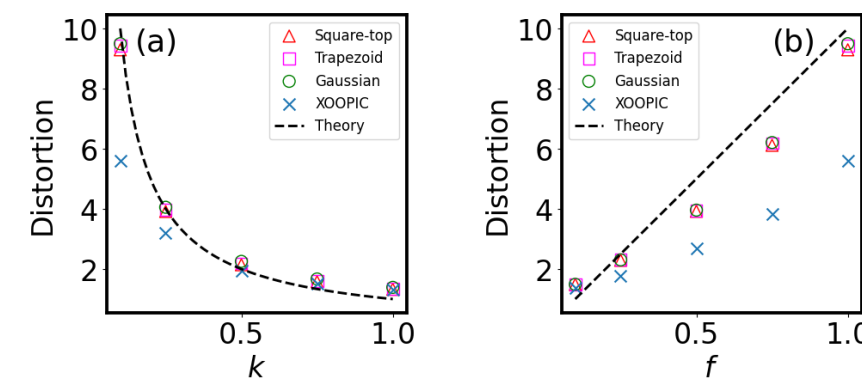


Figure 5: Beam distortion as a function of normalized pulse length for  $f = 1$  (a) and normalized charge density for  $k = 0.1$  (b), with comparison to PIC simulations using XOOPIC and the theoretical solution.

## Child-Langmuir limit

- We simulate Gaussian pulses with  $M = 30$  preloaded sheets. We fixed  $\delta\bar{x} = 1/M^2 = 1/900$ .

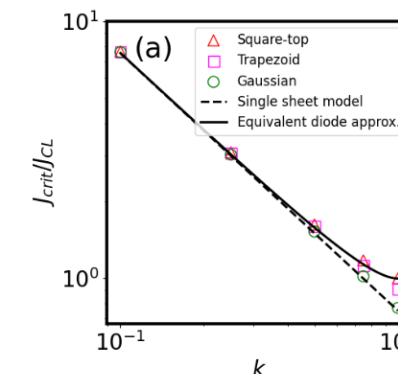


Figure 6: Normalized critical current density,  $J_{crit}/J_{CL}$ , as a function of the normalized pulse length.

- Single sheet model

$$J_{crit} = \frac{3J_{CL}}{4X_{CL}}$$

- Equivalent diode approximation

$$J_{crit} = 2 \frac{1 - \sqrt{1 - \frac{3}{4} X_{CL}^2}}{X_{CL}^3} J_{CL}$$

## Electron energy distribution at the anode

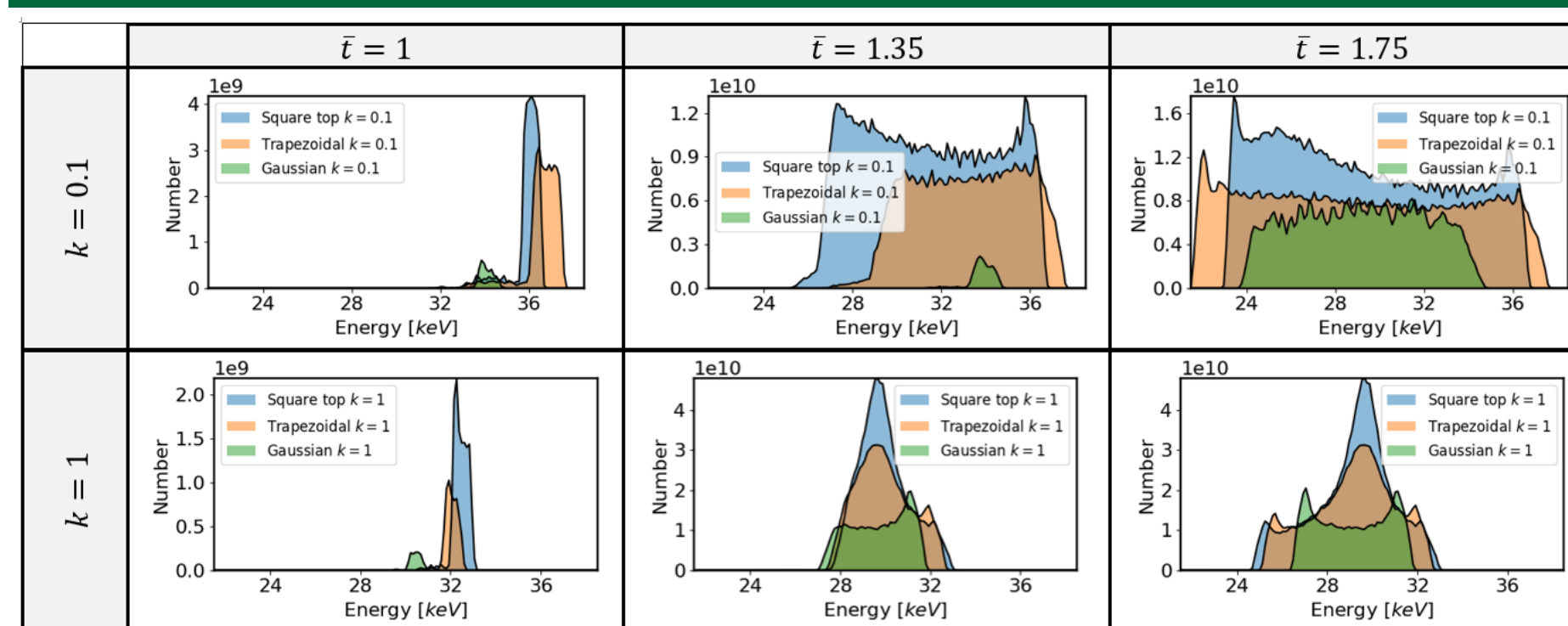


Figure 7: Electron energy distribution at the anode where  $\bar{t} = t/T_{CL}$

## Algorithm 1 Calculation of distortion

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Input:  $M, \delta\bar{x}$ 
1:  $\delta\bar{x}_{init} \leftarrow (M-1)\delta\bar{x}$ 
2:  $t \leftarrow 0$ 
3: while  $\bar{x}_1(t) < 1$  do
4:    $t \leftarrow t + 1$ 
5: end while
6:  $\delta\bar{x}_{final} \leftarrow \bar{x}_1(t) - \bar{x}_M(t)$ 
7:  $\Delta \leftarrow \delta\bar{x}_{final}/\delta\bar{x}_{init}$ 
8: return  $\Delta$ 

```

## Conclusion & Future Work

- For the **same total charge**, square-top and Gaussian pulses undergo **similar distortion** (fig. 5).
- The **shorter** the pulse length, the **more significant** the distortion becomes.
- The **smaller** the charge, the **faster** the tail of the pulse travels through the gap.
- The **Child-Langmuir limit** increases as the pulse length decreases.

## References & Acknowledgement

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